

650V SiC Schottky Diode

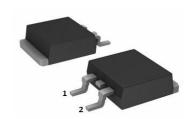
mp®

GP2D006A065C

VDC 650 V Q_C 14 nC I_E 6 A

Amp+™ Features

- High surge current capable
- Zero reverse recovery current
- · High bandwidth
- Fast, temperature-independent switching



Amp+™ Benefits

- Unipolar rectifier
- Zero switching loss
- · Higher efficiency
- Smaller heat sink
- Parallel devices with thermal stability

Amp+ ™ .	Applicat	tions
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- Motor drives
- Switch mode power supplies
- Power factor correction

Part #	Package	Marking
GP2D006A065C	TO-252-2L (DPAK)	2D006A065





Maximum Rating	Symbol	Conditions	Value	Unit	
		T _C =25 °C, T _j =175 °C	18		
Continuous forward current	I _F	T _C =125 °C, T _j =175 °C	10		
		T _C =150 °C, T _j =175 °C	6	А	
Surge non-repetitive forward current		T_{C} =25 °C, t_{p} =8.3 ms	48	A	
sine halfwave	I _{F,SM}	T_{C} =150 °C, t_{p} =8.3 ms	30		
Non-repetitive peak forward current	I _{F,max}	T_C =25 °C, t_p =10 μs	120		
.2.	∫i²dt	T_{C} =25 °C, t_{p} =8.3 ms	10	A ² s	
<i>i</i> ² <i>t</i> value	Ji at	T_{C} =150 °C, t_{p} =8.3 ms	4	AS	
Repetitive peak reverse voltage	V_{RRM}	T _j =25 °C	650	V	
Diode dv/dt ruggedness	dv/dt	Turn-on slew rate, repetitive	50	V/ns	
Power dissipation	P _{tot}	T _C =25 °C	65	W	
Operating & storage temperature	T _J , T _{storage}	Continuous	-55175	°C	
Soldering temperature	T _{solder}	Wave soldering leads	260	°C	
Mounting torque		M3 Screw	1	N-m	

Electrical Characteristics, at T_i=25 °C, unless otherwise specified

Static Characteristics	Symbol	Conditions	Values		Unit	
Static Characteristics	Symbol	Conditions	min.	typ.	max.	Oilit
DC blocking voltage	V_{DC}	I _R =0.1mA	650	-	-	
Diode forward voltage	V _F	I _F =6A, T _j =25 °C	-	1.45	1.65	V
Diode forward voltage	VF	I _F =6A, T _j =175 °C	-	1.65	2.00	
Reverse current	1	V _R =650V, T _j =25 °C	-	6.0	60	
	IR	V _R =650V, T _j =175 °C	-	100	600	μΑ

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$Amp + ^{TM}$

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Parameter	Symbol	Conditions	Values			Unit
raiailietei	Symbol	Conditions	min.	typ.	max.	Oilit

AC Characteristics

Total capacitive charge	Q _C	V _R =650V, T _j =25 °C	-	14	-	nC
Switching time		$di_F/dt=200 \text{ A/}\mu\text{s}$ $T_j=150 \text{ °C}$	-	-	<10	ns
Total capacitance		V _R =1 V, f=1 MHz	-	316	-	
	С	V _R =325V, f=1 MHz	-	pF		
		V _R =650V, f=1 MHz	-	23	-	

Thermal Characteristics

Thermal resistance, junction-case	R_{thJC}	Package (flange) mount	-	2.30	-	°C/W

Typical Performance

Fig. 1 Forward Characteristics (parameterized on T_i)

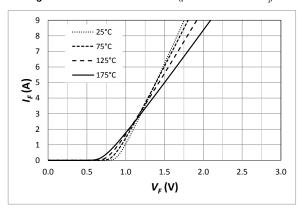


Fig. 2 Reverse Characteristics (parameterized on Tj)

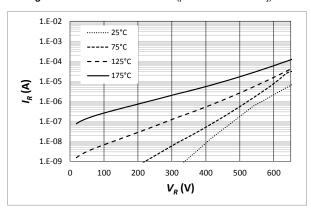


Fig. 3 Power Derating

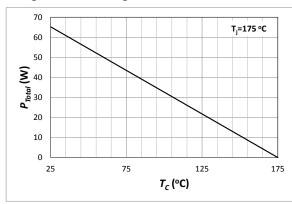


Fig. 4 Current Derating

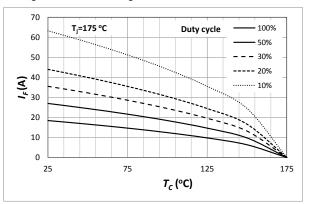


Fig. 5 Capacitance

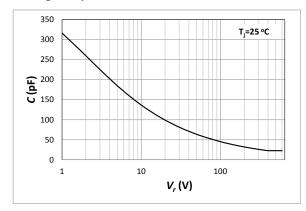
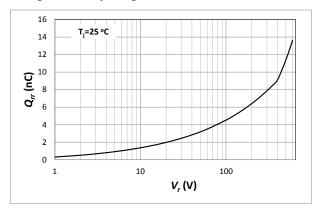
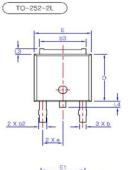


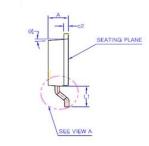
Fig. 6 Recovery Charge

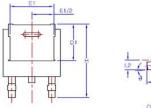


Package Dimensions

Package TO-252-2L (DPAK)









SYMBOL	MIN	NOM	MAX		
A	2.20	2.30	2.40		
A1 (▼)	0.00	-	0.127		
b	0.66	0.76	0.86		
b2	-	-	0.96		
b3	5.04	5.34	5.64		
c2	0.40	0.50	0.60		
D	5.90	6.10	6.30		
D1		(4.75)			
Ε	6.40	6.60	6.80		
E1	(5.04)				
e	2.30 BSC				
H	9.20	9.50	9.80		
L	1.27	1.47	1.67		
L1	2.50	2.70	2.90		
L2		0.508 BSC			
L3	0.50	0.70	0.90		
L4	0.60	0.80	1.00		
0	0°	-	10°		
01	(5°)				

(* NOTE)

- 1. THESE DIMENSIONS DO NOT INCLUDE PROTRUSIONS OF THE MOLD. 2. THE "()" MARK IS THE REFERENCE 3. COPLANARITY: MAX. () IONNO 4. THE "L4" SYMBOL IS A PROTRUSION OF THE LEAD FRAME.

The levels of RoHS restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2011/65/EC (RoHS2), as implemented March, 2013. RoHS Declarations for this product can be obtained from the Product Documentation sections of www.gptechgroup.com.

REACH Compliance
REACH substances of high concern (SVHCs) information is available for this product. Since the European Chemi- cal Agency (ECHA) has published notice of their intent to frequently revise the SVHC listing for the foreseeable future, please contact our office at GPTG Headquarters in Lake Forest, California to insure you get the most up-to-date REACh SVHC Declaration. REACh banned substance information (REACh Article 67) is also available upon request.

This product has not been designed or tested for use in, and is not intended for use in, applications implanted into the human body nor in applications in which failure of the product could lead to death, personal injury or property damage, including but not limited to equipment used in the operation of nuclear facilities, life-support machines, cardiac defibrillators or similar emergency medical equipment, aircraft navigation or communication or control systems, or air traffic control.

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